



Traitement intégré d'ondes de matière

Jakob Reichel

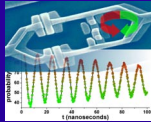
Max-Planck-Institut für Quantenoptik
et Ludwig-Maximilians-Universität München





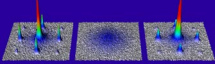
Increasing interaction of Quantum Optics and Solid-State physics

Quantum optical concepts + condensed-matter systems:




SQUIDS, Cooper-pair boxes, quantum dots: "artificial atoms", Rabi oscillations, controlled coupling, ...
e.g. cond-mat/0402216: [cavity QED](#)
with superconducting stripline resonator + Cooper pair box

Condensed-matter concepts + cold atomic systems:



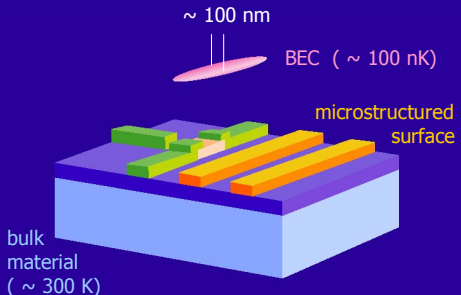
Bloch oscillations, Mott insulator, ...
Kondo effect, Bose glass...
general quantum simulation

Cold atomic systems + condensed-matter systems:



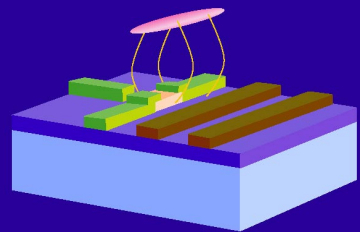
Atom chips

Atom chips: BEC meets the nanoworld



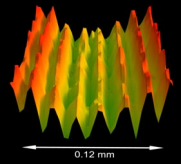
~ 100 nm
BEC (~ 100 nK)
microstructured surface
bulk material (~ 300 K)

Atom chips: BEC meets the nanoworld



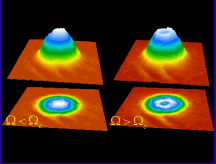
1. BEC on a chip
2. Coherent atom manipulation
3. Controlling atom-surface interactions

An atomic Bose-Einstein condensate is...



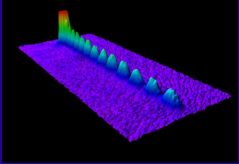
MIT

a matter wave...



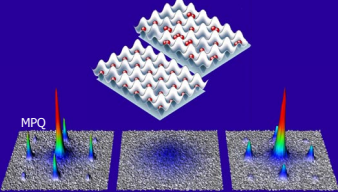
ENS

a superfluid...



MPQ

an atom laser...

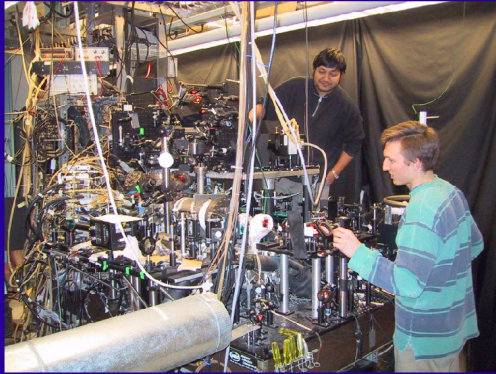


MPQ

...a many-body quantum system

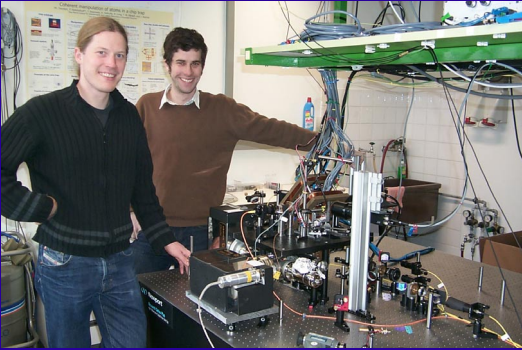
BEC was hard work...

1995	JILA	Rb
	MIT	Na
1995/97	Rice	Li
.	---	
.		
1997	first follow-ups	

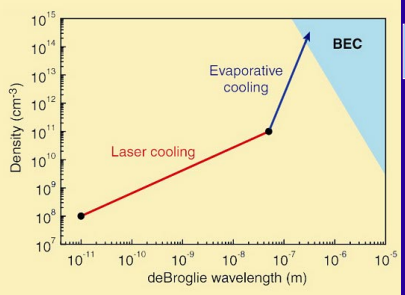



MIT BEC apparatus

... it has become much easier





The route to BEC





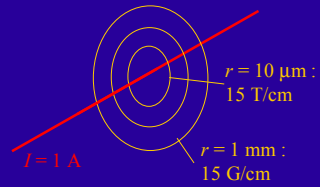
300 K 10 μK 500 nK



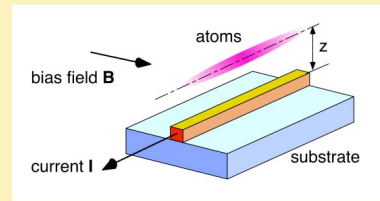


Magnetic Chip Traps ("Atom Chips")

$$\nabla B = \frac{\mu_0 I}{2\pi r^2}$$



Magnetic Microchip Traps

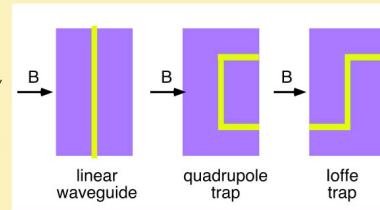


related:

superconducting microtrap (theoretical):
J. D. Weinstein, K. G. Libbrecht, PRA 52, 4004 (1995)

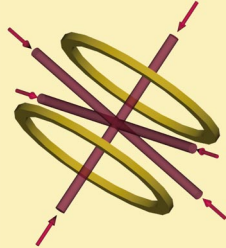
wire traps:
Schmiedmayer group, Zimmermann and Hänsch grps.

waveguides:
Prentiss and Westervelt grps., Anderson and Cornell grps.

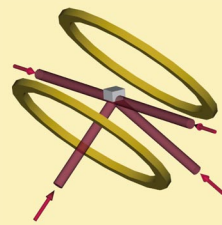


J. Reichel, W. Hänsel, and T. W. Hänsch, PRL **83**, 3398 (1999).

Solving the Loading Problem



standard MOT



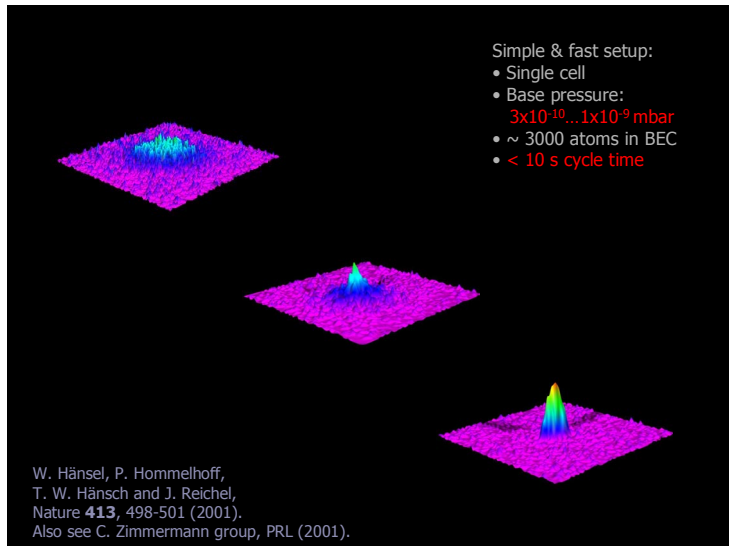
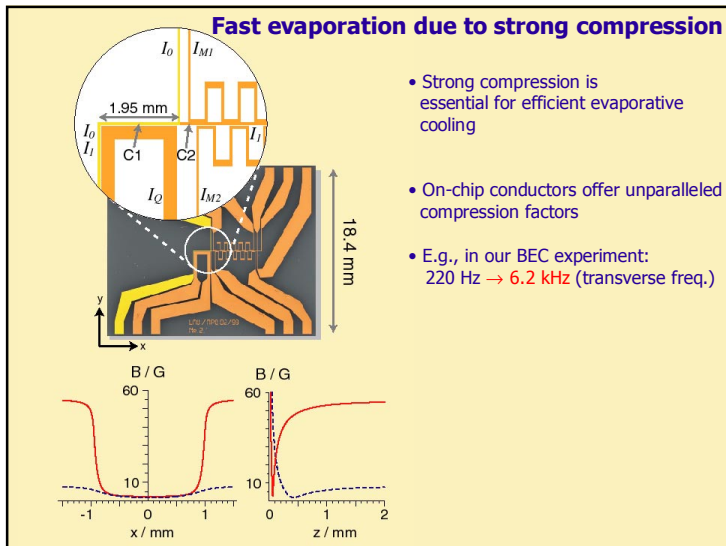
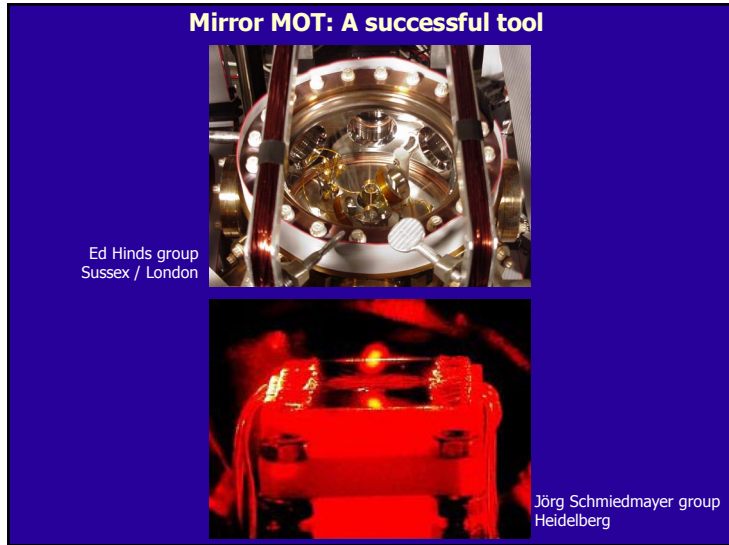
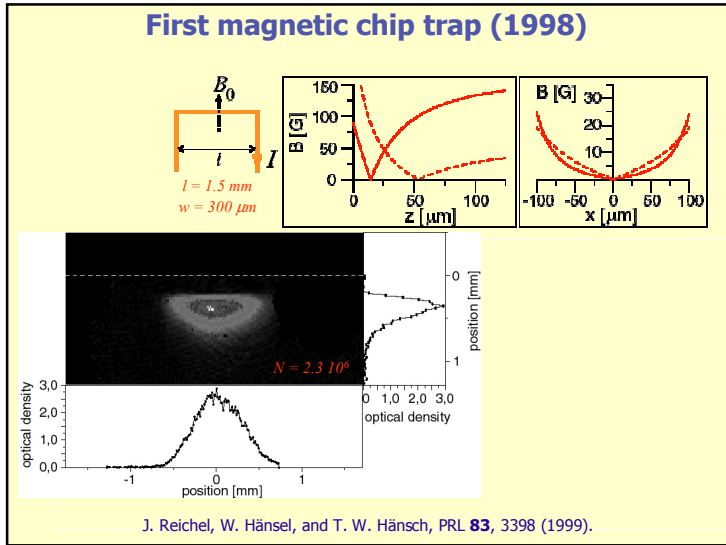
mirror MOT




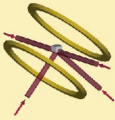
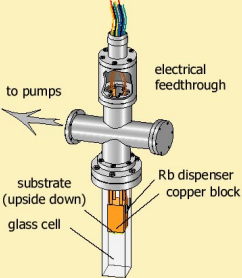
J. Reichel, W. Hänsel, and T. W. Hänsch, PRL **83**, 3398 (1999).
Details: J. Reichel, Appl. Phys. B **74**, 469 (2002).

Example: Magnetic Conveyor chip







All You Need for BEC:

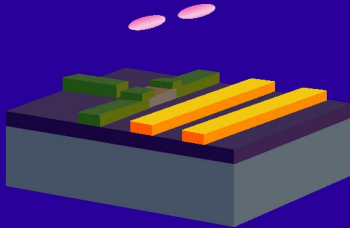
<p>chip</p>  <p style="text-align: center;">~25 mm</p> <ul style="list-style-type: none"> • Many commercial processes do the job 	<p>mirror-MOT</p>  <ul style="list-style-type: none"> • Master / Slave trap, pump, detect 70 mW total • Repumper few mW 	<p>simple vacuum system</p>  <ul style="list-style-type: none"> • $\sim 5 \times 10^6$ atoms in MOT, 3.4×10^6 atoms in magnetic trap • $\tau \sim 5 \dots 10$ s mag. trap lifetime, base pressure $\sim 3 \times 10^{-10} \dots 1 \times 10^{-9}$ mbar • $\sim 3 \times 10^3$ atoms in BEC • < 10 s cycle time
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Chip BEC

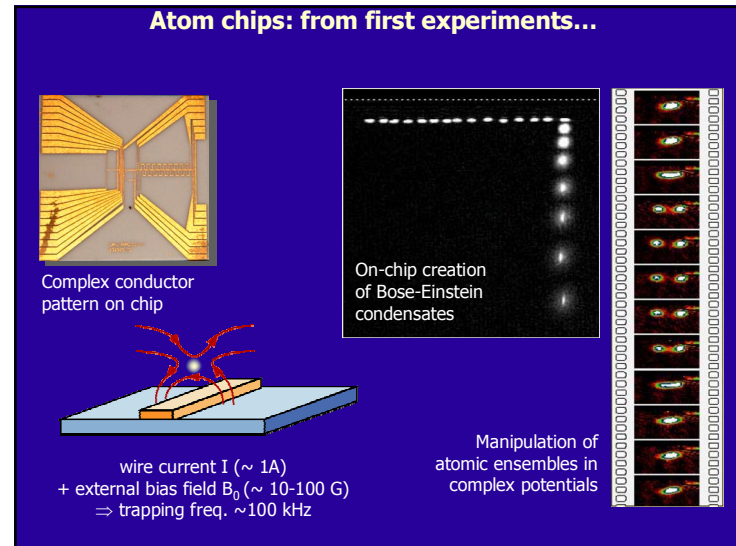
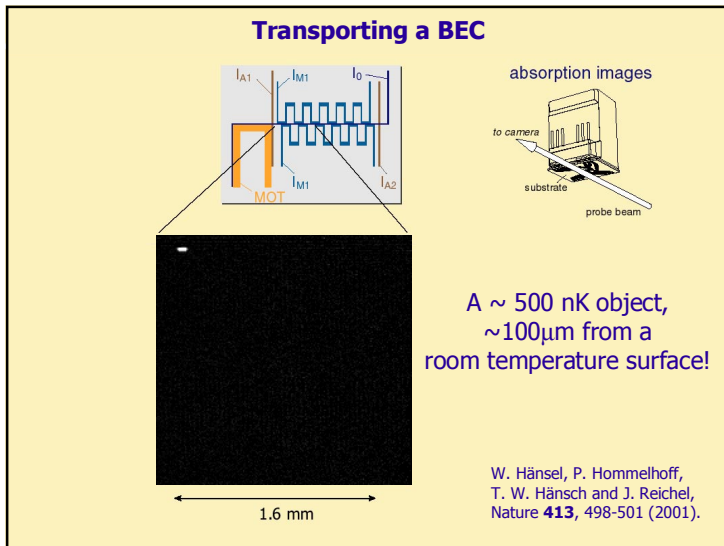
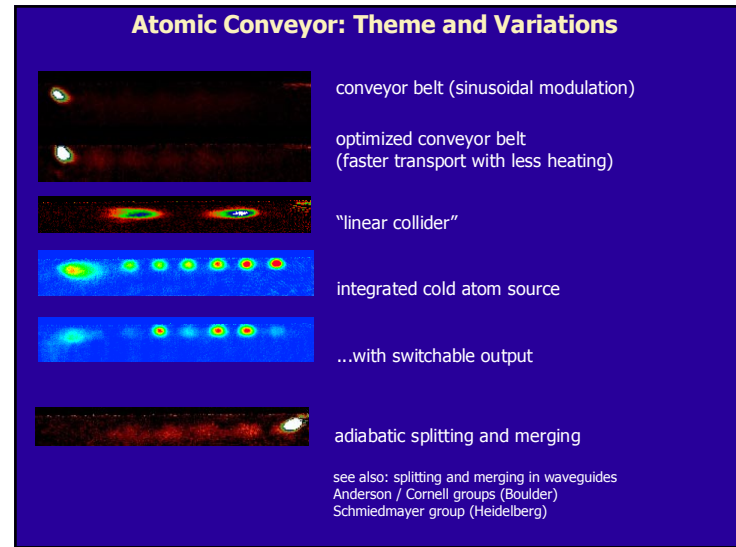
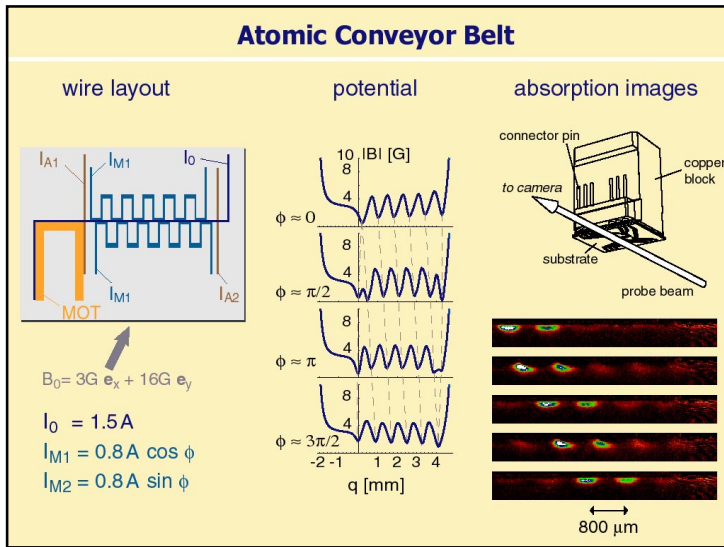
- Atom chips: Easy & fast way to create BECs.
- Exceptionally strong confinement – 1 MHz trapping freq. is possible.
- The method is rapidly spreading in the community:
 - 2001: First 2 chip BECs (our group & independent, simultaneous work in C. Zimmermann's group, Tübingen)
 - 2003: ≥ 8 chip BECs worldwide, > 10 more coming
- With atom chips, BEC is ready for applications – can even be portable.

Atom chip for BEC in microgravity

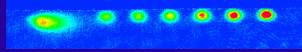
 <p>Bremen drop tower: 4.7 s of microgravity</p>	 <p>Portable BEC apparatus will be installed in capsule. Experiment is "powered" by MPQ atom chip.</p>
<p>Consortium: U Hannover, U Hamburg, HU Berlin, U Ulm, MPQ Assembly scheduled for 2005</p>	



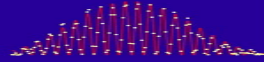
2. Coherent atom manipulation



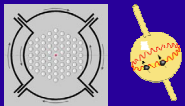
... towards an integrated quantum laboratory



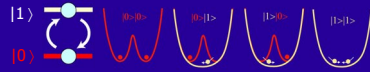
Atoms in complex potentials
Josephson effect
BEC in ring traps
1D quantum gases



Interferometry and precision measurement
On-chip atomic clocks
Inertial sensors
Measurement of surface forces



Microcavities on chip
Cavity QED
Single atom detection



Quantum information processing with neutral atoms in microtraps

Why QIP with neutral atoms?

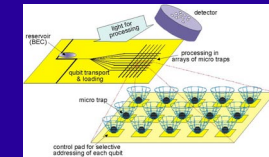
Weak coupling to the environment

Coherence lifetimes $\tau_{\text{coh}} \sim$ seconds

$\tau_{\text{coh}} \sim 10^4 - 10^5 \tau_{\text{gate}}$ required for quantum error correction

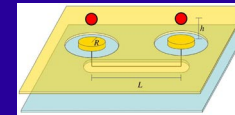
Scalable manipulation techniques

- Atom chips provide tailored potentials
- Integration of many traps in parallel



Proposal by J. Schmiedmayer *et al.*, J.Mod.Opt. **49**, 1375 (2002)

Integration with solid-state systems possible



Coupling of Atoms to superconductor on chip

Proposal by A.S. Sorensen *et al.*, PRL **92**, 063601 (2004)

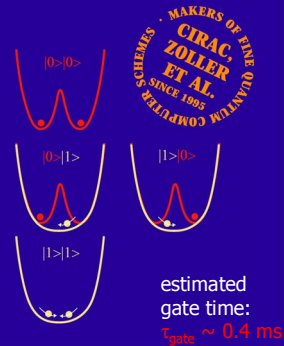
Atom chip QIP: Collisional phase gate proposal

Phase gate:

$$\begin{aligned} |0\rangle|0\rangle &\Rightarrow |0\rangle|0\rangle \\ |0\rangle|1\rangle &\Rightarrow |0\rangle|1\rangle \\ |1\rangle|0\rangle &\Rightarrow |1\rangle|0\rangle \\ |1\rangle|1\rangle &\Rightarrow -|1\rangle|1\rangle \end{aligned}$$

Ingredients:

- Single qubit operations
- Long coherence lifetime close to chip surface
- Strongly confining, state-dependent potential
- Single atom preparation and detection



estimated gate time:
 $\tau_{\text{gate}} \sim 0.4$ ms

D. Jaksch *et al.*, PRL **82**, 1975 (1999).
T. Calarco *et al.*, PRA **61**, 022304 (2000).

Goal of our current experiments:

Full coherent control on the single-particle level

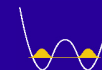


Internal states

First experiments with coherent superpositions on chip
- Qubit rotations and chip clocks



Measurement and control of small atom numbers



External states

Single atoms and BECs in a double well



Coherence of internal states

...is essential in in QIPC with internal-state qubits, but also in atomic clocks

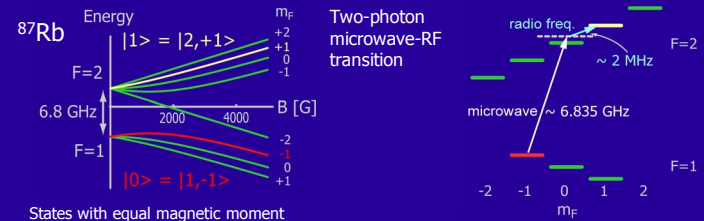
...is more delicate to handle in traps than for untrapped atoms

Good choice for magnetic trapping: $|1,-1\rangle, |2,1\rangle$ (^{87}Rb)

2 s coherence time has been demonstrated
D.M.Harber, H.J.Lewandowski, J.M.McGuirk, and E.A.Cornell, PRA **66**, 053616 (2002)

Decoherence induced by the surface?

Single qubit rotations

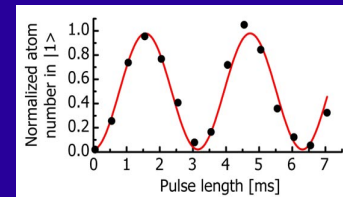


States with equal magnetic moment
• experience same trapping potential
• robust against decoherence

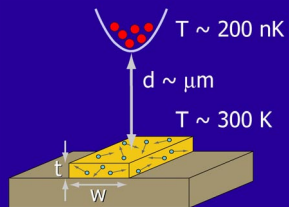
Rabi oscillation (qubit rotation):



20,000 atoms in $F = 1, m_F = -1$
15 W microwave power
~ 1 W RF power
1.2 MHz intermediate state detuning
 $\Omega_{\text{Rabi}} \sim 0.2 - 1$ kHz: eff. two-photon Rabi frequency



Surface decoherence and loss?

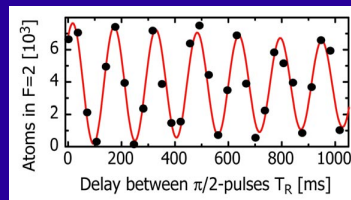


Loss and decoherence due to magnetic near-field noise

(Theory by C. Henkel et al., 1999-2003)

In our experiment at $d = 9 \mu\text{m}$:
 $\Gamma_{\text{dec}} \sim 10^4$ Hz (states with equal magn. moment)
 $\Gamma_{\text{loss}} \sim 0.2$ Hz (thin conductors)

Coherence measurements: Ramsey spectroscopy

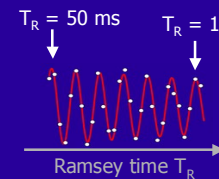


coherence lifetime ($d = 9 \mu\text{m}$):

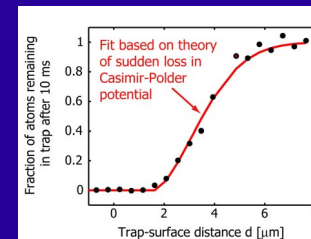
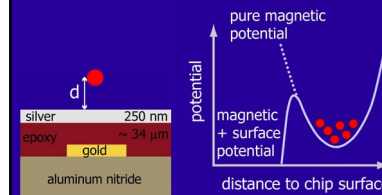
$$\tau_{\text{coh}} = 2.8 \text{ s} \sim 10^4 \tau_{\text{gate}}$$

similar to experiments in macroscopic magnetic traps (Cornell group, Boulder)

Surface decoherence and loss?




Casimir-Polder surface potential modifies the trap:



The way to atom-chip quantum gates

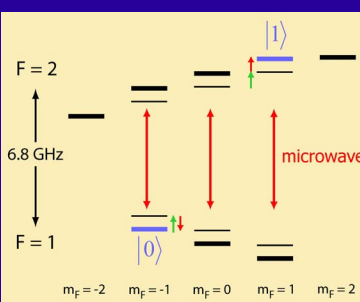
1. Single qubit rotations ✓
2. Long coherence times ✓
3. State selective potentials ?



$|F=1, m_F=-1\rangle$ and $|F=2, m_F=+1\rangle$

⇒ identical Zeeman effect in static B-fields
 ⇒ identical Stark shift in static E-fields
 ⇒ identical AC Stark shift ($\hbar\Delta \gg E_{\text{HFS}}$)

State selective microwave potentials "AC Zeeman effect"



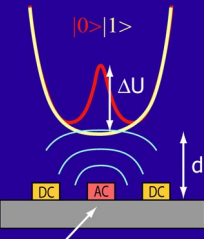
Coupling of levels with microwaves:
 $\hbar\Omega_R \sim \mu_B B_{\text{mw}}$

Energy shift (AC Zeeman):
 $U_{g/e} = \pm \frac{\hbar\Omega_R^2}{4\Delta}$, ($|\Delta| \gg \Omega_R$)

Microwave coupling leads to state-dependent energy shift!

Microwave near-fields on the atom chip

see Ph. Treutlein et al., quant-ph/0311197 (2003)



Atoms at $d \ll \lambda_{\text{mw}}$ are subjected to the near-field of the wire

⇒ state-dependent potentials varying on the micron-scale


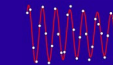
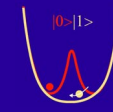
wire carrying DC + microwave current

microwave current $I_{\text{mw}} = \pm 10$ mA
 distance $d = 5 \mu\text{m}$
 detuning $\Delta = 100 \text{ MHz} \times 2\pi$

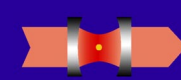
⇒ potential barrier $\Delta U/\hbar > 100 \text{ kHz}$

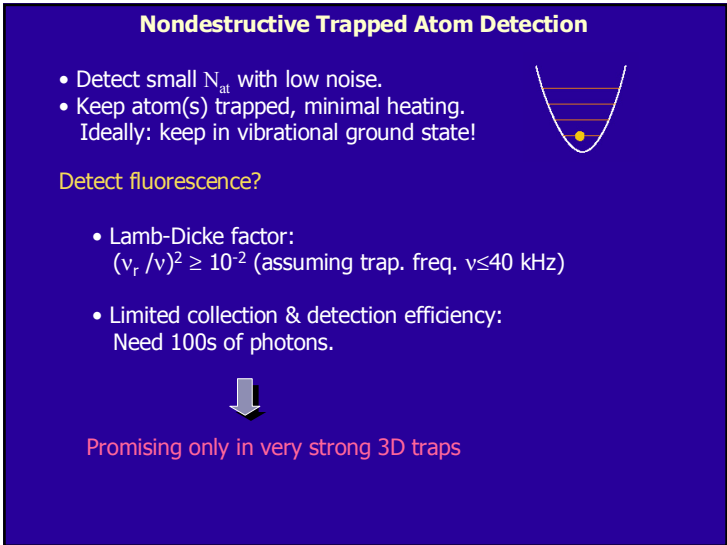
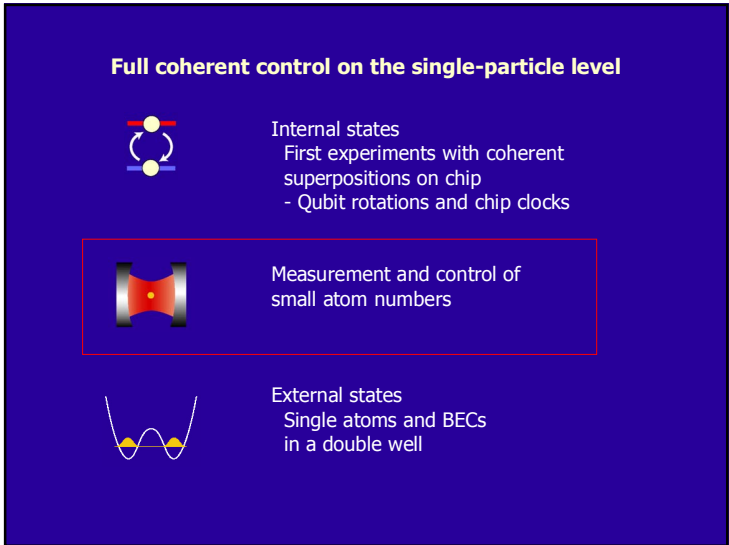
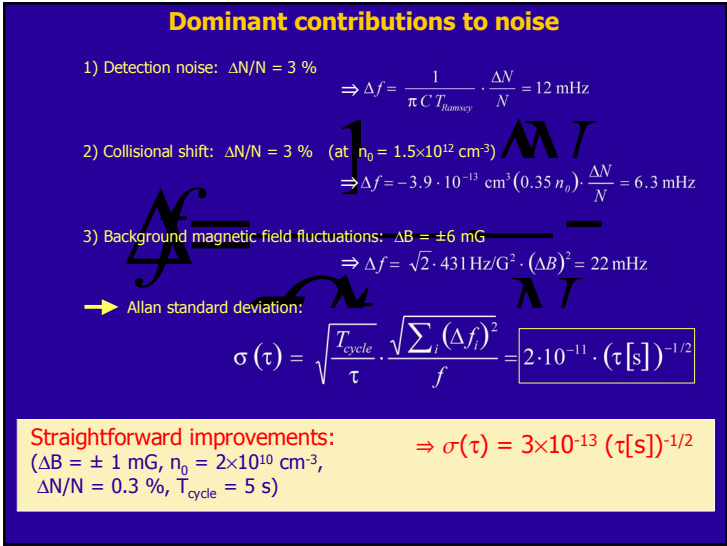
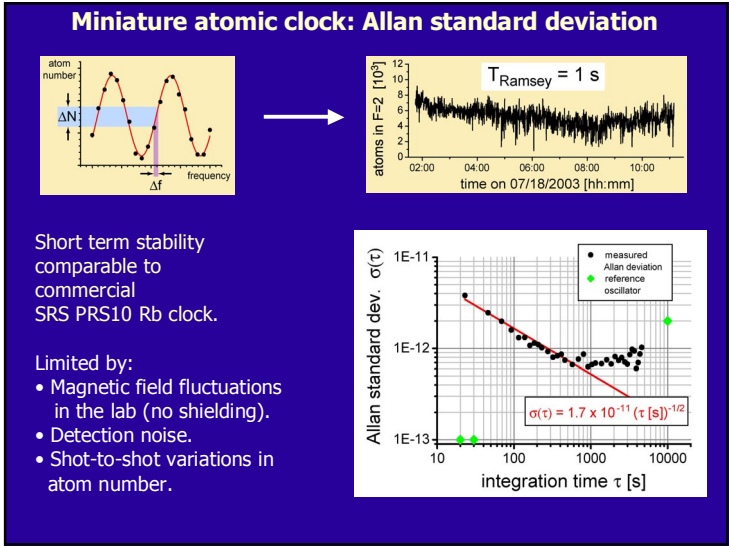
⇒ magnetic moments of $|0\rangle, |1\rangle$ change only by $\Delta\mu < 10^{-3} \mu_B$

Towards atom-chip quantum gates

- Single qubit rotations ✓ 
- Long coherence times ✓ 
- State selective potentials ? 

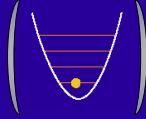
Microwave atom chips:
 Ph. Treutlein, P. Hommelhoff, T. Steinmetz, T. W. Hänsch & J.R., quant-phys/0311197

- Preparation and detection ? 



Dispersive Trapped Atom Detection

- Phase shift from single atom is detectable
- However, a resonator is required to avoid spontaneous emission



R.Long, T.Steinmetz, P.Hommelhoff, W.Hänsel, T.W.Hänsch and J. Reichel, Phil. Trans. Roy. Soc. A **361**, 1375 (2003).



Trapped atoms in an optical resonator
(versatile system!)

Dispersive atom detection with a resonator

Signal-to-noise ratio:

$$\mathcal{Q} = \frac{\Delta\Phi_{at}}{\Delta\Phi_{noise}} = \sqrt{\frac{g^2}{\kappa\gamma}} \sqrt{\frac{T}{T+A}} \sqrt{\frac{\xi}{2}} \sqrt{N_{sp}}$$

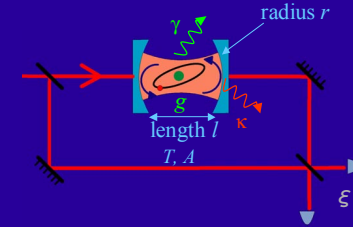
detectable signal: $\mathcal{Q} \geq 1$

no spont. emission: $N_{sp} \ll 1$

To obtain $N_{sp}=0.1$ with $\mathcal{Q}=1$ and detector efficiency $\xi=0.6$, need

$$\sqrt{\frac{g^2}{\kappa\gamma}} \sqrt{\frac{T}{T+A}} \approx 6.3$$

FP for cavity QED (CalTech)	14
Microsphere (ENS)	8
...	...



Stable Fabry-Pérot resonator:

$$\mathcal{Q} \propto \sqrt{\frac{\mathcal{F}}{\sqrt{r}l}} \sqrt{\frac{T}{T+A}} \sqrt{N_{sp}}$$

Closely related to optical cavity QED situation (Rempe, Kimble groups) but with magnetically trapped atoms.

Problem: Macroscopic mirrors used in cavity QED are too large for us!

Resonator detectors: Different approaches

Whispering Gallery Mode (WGM) in a silica microsphere
In collaboration with ENS Paris

Fiber resonator
Stable resonator (concave mirrors),
Finesse > 2000

Also pursued in Heidelberg, Southampton (ACQP collaboration) ...

Fiber-Fabry-Pérot Resonator

single-mode fiber
coated fiber end faces
125 μ m
multi-mode fiber

Advantages:
- compact
- easy coupling
- resonator axis <100 μ m from chip surface
- exceptionally small mode volume

Coating the fibers: Transfer technique

intermediate substrate
fiber
transparent epoxy
dielectric mirror
Spherical mirrors:
Use sphere as intermediate substrate!
mirror coating on fiber end face

Spherical fiber Fabry-Pérot resonator: Properties

Piezo tuning, (two-freq. calibration):

FSR \sim 15THz
 \Rightarrow resonator length \sim 10 μ m
 Mirror curvature R=1mm
 \Rightarrow Mode cross-section \sim 10 μ m
 \Rightarrow Coupling $g/2\pi \sim$ 400 MHz

FSR \sim 13,5GHz
 \Rightarrow Finesse: \sim 1100

Transmission/reflection measurement:

Each mirror:
 - transmission $T \sim 5 \cdot 10^{-4}$
 - losses $A \sim 3 \cdot 10^{-3}$

\Rightarrow Faser-Fabry-Pérot-Resonator

$$\frac{g}{\sqrt{\kappa\gamma}} \sqrt{\frac{T}{T+A}} \approx 0.8$$

Piezo voltage [a.u.]
FSR \sim 15THz
FWHM \sim 13.5GHz

Fiber resonator on the chip

~25mm
detector position
magn. transport
MOI
x10
x10
waist
R=1mm
1.8 μ m

Full coherent control on the single-particle level

Internal states
 First experiments with coherent superpositions on chip
 - Qubit rotations and chip clocks

Measurement and control of small atom numbers

External states
 Single atoms and BECs in a double well

BEC in Magnetic Double Well

- Josephson oscillations in BECs, "self-trapping"
- essence of Mott insulator transition
- Trapped-atom interferometer
- Collisional phase gate

on-site interaction $\propto g\beta$

tunneling $\propto \gamma$

$$H = \gamma(a_L^\dagger a_R + a_R^\dagger a_L) + g\beta / 2 [(a_L^\dagger a_L)^2 + (a_R^\dagger a_R)^2]$$

Trapped-Atom Interferometer

split trapping potential

single atom in trap ground state

phase evolution (manipulation)

atom in superposition state

merge trapping potentials

atom in superposition state

single atom in the ground state or 1st excited state

Single-atom device (requires single-atom detector)
W. Hänsel, J.Reichel, P.Hommelhoff and T.W.Hänsch, Phys.Rev.A **64**, 063607 (2001).

Split BEC on our current Chip: Large Well Separation

unsplit

$I_0 = 1.9 \text{ A}$

split

$I_0 = 1.82 \text{ A}$

4 ms

21 ms

21 ms, smaller spacing

$\lambda = h v / m d \sim 1.6 \mu\text{m}$

⇒ can't resolve fringes – use new substrate, ~ 3 μm features

A Conductor Layout for a Magnetic Double Well

$I_0 = 525 \text{ mA}$
 $B_{0,y} = 20 \text{ G}$
 $B_{0,x} = 16 \text{ G}$
 $I_{\text{ext}} = 140 \text{ mA} + 2.91 \text{ mA} \cdot s$
 $I_C = 0.25 \text{ mA} + 4.4 \text{ mA} \cdot s$

magnetic field

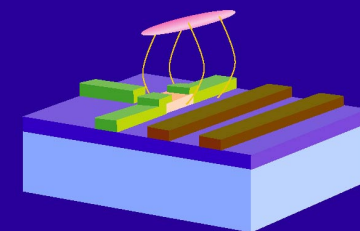
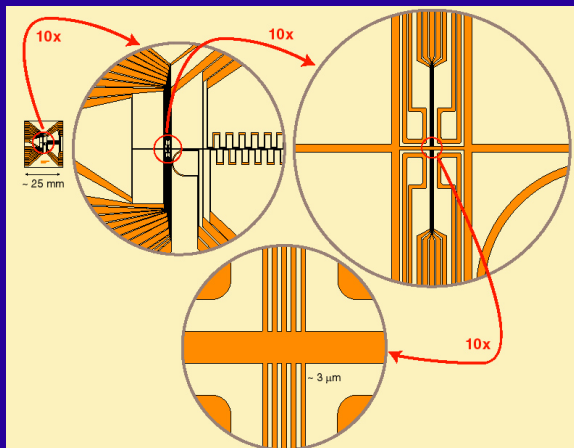
single well (s=0)

two wells (s=1)

wave functions

Double-well chip

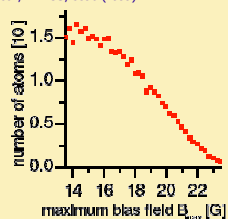
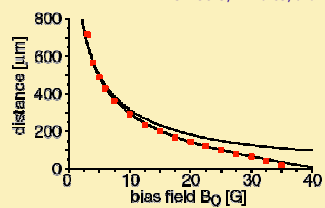
In collaboration with Ben Lev, Hideo Mabuchi (CalTech)



3. Controlling atom-surface interactions

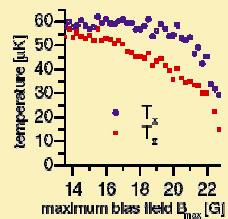
Surface-induced evaporation

J. Reichel, W. Hänsel, and T. W. Hänsch, PRL **83**, 3398 (1999).



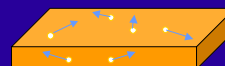
Recently, BEC has been achieved with this cooling mechanism:

D. Harber et al. (E. Cornell group), J. Low Temp. Phys. **133**, 229 (2003).



Interactions of ultracold atoms with a room-temperature surface

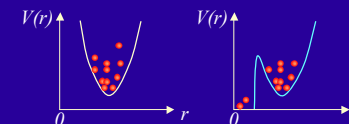
- Unexplored area of atom-surface physics
- Theoretical work by C. Henkel et al., 1999-2003



thermal currents in bulk metal
 \Rightarrow fluctuating magnetic fields
 \Rightarrow spin flips in trapped atoms
 \Rightarrow trap loss



no such effect in dielectrics
 \Rightarrow Casimir-Polder potential dominant
 \Rightarrow apparent surface level is raised



How close can the cold atoms be brought to the surface?

- **Metal surfaces:** Fluctuating, thermally excited currents in the surface cause trap loss.
- **Dielectric surfaces:** No such effect. Casimir-Polder potential can be observed.

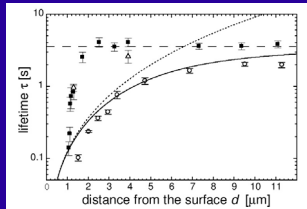
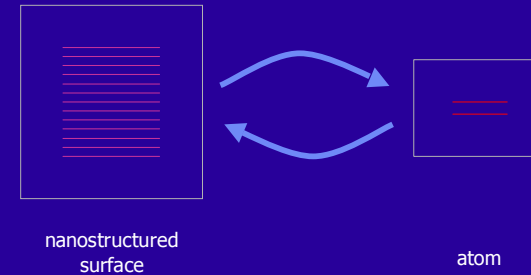


FIG. 4: Trap Lifetime as a function of distance from a dielectric (solid squares) and metal (open circles) surface, for $T=1.0 \mu\text{K}$ and $B_0=0.57 \text{ G}$. The dotted line is the calculated lifetime above the metal due to thermal B fields only, the solid line includes the one-body lifetime of 3.5 s (dashed line). The open triangles are measurements for a pure condensate above the dielectric.

V. Vuletic group,
Stanford (now MIT)

Coherent atom-surface interactions?



Vision: Coherent interaction with mesoscopic solid-state system

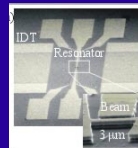
BEC on chip could be used as

- quantum actuator
- quantum probe

("quantum"=all degrees of freedom are controlled on the quantum level).

Couple atoms to mesoscopic solid-state systems:

- Spin detection
- Fundamentals of detection and decoherence: A coherent two-level system coupled to an engineered, mesoscopic, solid-state system



Nanomechanical resonator
J. Kotthaus group, CENS/LMU

The Microtrap Team

Tilo Steinmetz
Philipp Treutlein

Rémi Delhulle
Romain Long

Theodor W. Hänsch
JR



Frequent guest:
Benjamin Lev
(Mabuchi group, CalTech)

Former members:
Peter Hommelhoff
(now Stanford)
Wolfgang Hänsel
(now Innsbruck)

Diploma students
Christian Sartena
Chiara Chiffi
Tim Rom
Astrid Richter

PhD and postdoc positions available!

